

CWDM (1270nm~1610nm) DFB Coaxial laser diode module

Features

- Advanced Multiple Quantum Well (MQW) laser
- Distributed Feedback (DFB) Laser Design
- Low Threshold Current
- Built-in InGaAsP monitor PD
- Cost-effective Uncooled Laser Technology
- 5.6-mm TO-style Package with SMF coupling

Application

- CATV Return-Patch
- Analog Transmission
- Light Source
- Sensor
- Optical telecommunication
- OTDR

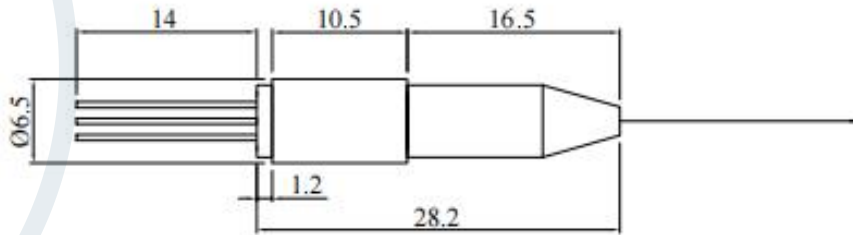
Absolute Maximum Ratings (Tc=25°C .unless otherwise specified)

Parameter	Symbol	Min.	Max.	Unit	Test Condition
Laser Forward Current	I _{FP}	-	-	120	mA
Reverse Voltage	V _R		2	V	CW
Operating Temperature	T _{OP}	-20	+70	°C	
Storage Temperature	T _{stg}	-40	+100	°C	-
Soldering Temperature/Time	-		260/10	°C/S	-

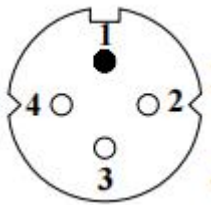
Optical & electrical characteristics (T_c=25°C)

Parameter	Symbol	Min	Typ.	Max.	Unit	Test Conditions
Optical Output Power	P _o	1.0	–	5.0	mW	CW,DFB,25°C
Threshold Current	I _{th}		10	15	mA	DFB,25°C
Operating Current	I _{op}	–	20	50	mA	CW,P _o =2mW,DFB,25°C
		–	45	75		CW,P _o =2mW,DFB,70°C
Forward Voltage	V _F	–	1.1	1.6	V	CW,P _o =2mW,25°C
Center Wavelength	λ _c	1307	1310	1313	nm	CW, DFB,25°C
		1547	1550	1553		
		λ _c -3	λ _c	λ _c +3		
Spectral Width (-20 dB)	Δλ	–	0.5	–	nm	CW, 25°C
Side Mode Suppression Ratio	SMSR	30	40	–	dB	25°C
Monitor Dark Current	I _D	0.08	0.5	–	mA	CW, I _{th} +20mA
Optical Isolation	ISO	30	–	–	dB	25°C
Modulation Bandwidth	BW	1.25	–	–	GHz	-3dB,P _o =2mW
Rise Time/ Fall Time	TR/TF	–	0.3	0.7	ns	CW, I _{th} +20mA

Dimensions(mm)



Pin Assignment



	Type A		Type C
1	LD + / Case	1	Case
2	LD -	2	LD -
3	PD -	3	PD +
4	PD +	4	LD + / PD -

Order Information

GTA1015

“O Wavelength” 1270nm ~ 1410nm.

“ S+C+L Wavelength” 1430nm ~ 1610nm.



Please let us know your request details before order.



Customize for you

